

Appl. No. 10/605,015  
Amdt. dated October 21, 2005  
Reply to Office action of August 02, 2005

**Amendments to the Specification:**

Please replace the original title with the following new title:

STACKED CAPACITOR HAVING PARALLEL INTERDIGITIZED STRUCTURE FOR  
USE IN THIN FILM TRANSISTOR LIQUID CRYSTAL DISPLAY

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Please replace the original abstract with the following new abstract:

A capacitor ~~structure includes~~ structure includes a first conductive  
layer, a first insulating layer disposed on a substrate in sequence, a second  
conductive layer disposed on portions of the first insulating layer, a second  
10 insulating layer disposed on the second conductive layer and the first  
insulating layer, a third conductive layer disposed on portions of the  
second insulating layer, a third insulating layer disposed on the third  
conductive layer and the second insulating layer, ~~[[anda]]~~ and a fourth  
conductive layer disposed on the third insulating layer. The third  
15 conductive layer and the fourth conductive layer are electrically connected  
to the first conductive layer and the second conductive layer through at  
least one first contact hole adjacent to the second conductive layer and at  
least one second contact hole, respectively.